

Title (en)

SOLAR CELL AND METHOD FOR MANUFACTURING THE SAME

Title (de)

SOLARZELLE UND VERFAHREN ZUR HERSTELLUNG DAVON

Title (fr)

CELLULE SOLAIRE ET SON PROCÉDÉ DE FABRICATION

Publication

**EP 3240045 A1 20171101 (EN)**

Application

**EP 17173972 A 20100211**

Priority

- KR 20090012024 A 20090213
- EP 15002930 A 20100211
- EP 10741395 A 20100211
- KR 2010000858 W 20100211

Abstract (en)

A solar cell and a method for manufacturing the same are disclosed. The solar cell includes a semiconductor layer containing first impurities, a first portion positioned on a first part of one surface of the semiconductor layer, the first portion being more heavily doped with second impurities different from the first impurities than the semiconductor layer, a second portion positioned on a second part of the one surface of the semiconductor layer, the second portion being more heavily doped with the first impurities than the semiconductor layer, and a third portion positioned between the first portion and the second portion, the third portion having an impurity concentration lower than an impurity concentration of the first portion and an impurity concentration of the second portion.

IPC 8 full level

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Citation (search report)

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- [A] NIJS J ET AL: "Overview of solar cell technologies and results on high efficiency multicrystalline silicon substrates", SOLAR ENERGY MATERIALS AND SOLAR CELLS, ELSEVIER SCIENCE PUBLISHERS, AMSTERDAM, NL, vol. 48, no. 1-4, 1 November 1997 (1997-11-01), pages 199 - 217, XP004111851, ISSN: 0927-0248, DOI: 10.1016/S0927-0248(97)00103-7

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**US 2010206369 A1 20100819; US 9054240 B2 20150609**; EP 2359412 A2 20110824; EP 2359412 A4 20120926; EP 2359412 B1 20151021;  
EP 2993703 A1 20160309; EP 2993703 B1 20170719; EP 3240045 A1 20171101; EP 3240045 B1 20190918; KR 101099480 B1 20111227;  
KR 20100092746 A 20100823; US 10043933 B2 20180807; US 2015255645 A1 20150910; US 2018323328 A1 20181108;  
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